

D

G

Drain

**Schematic Diagram** 

D D

DFN2X2-6L bottom view

G

Source

## NCE N-Channel Enhancement Mode Power MOSFET

## Description

The NCE3013J uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

### **General Features**

- V<sub>DS</sub> =30V,I<sub>D</sub> =13A
  - $R_{DS(ON)} < 12m\Omega @ V_{GS} = 10V$
  - R<sub>DS(ON)</sub> <20mΩ @ V<sub>GS</sub>=4.5V
- High density cell design for ultra low Rdson
- Fully characterized Avalanche voltage and current
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

#### Application

- Power switching application
- Hard Switched and High Frequency Circuits
- Uninterruptible Power Supply

### Package Marking and Ordering Information

r dekage marking and ordering information							
Device Marking	Device	Device Package	Reel Size	Tape width	Quantity		
3013J	NCE3013J	DFN2X2-6L	Ø180mm	12mm	4000 units		

### Absolute Maximum Ratings (Tc=25°Cunless otherwise noted)

	Parameter	Symbol	Limit	Unit
Drain-Source Voltage		Vds	30	V
Gate-Source Voltage		Vgs	±20	V
Drain Current-Continuous		I <sub>D</sub>	13	А
Drain Current-Continuous(	T <sub>C</sub> =100℃)	I <sub>D</sub> (100℃)	9.2	А
Pulsed Drain Current (Note 1)		I <sub>DM</sub>	52	А
Maximum Power Dissipation		PD	3	W
Single pulse avalanche energy (Note 5)		E <sub>AS</sub>	72	mJ
V <sub>DS</sub> Spike (Note 6)	10µs	36	36	
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55 To 150	°C
Thermal Characteris	tic	· · · · · · · · · · · · · · · · · · ·	·	

# Thermal Resistance, Junction-to-Ambient<sup>(Note 2)</sup> R<sub>0JA</sub> 42 °C/W

Parameter	Symbol	Condition	Min	Тур	Max	Unit	
Off Characteristics							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	30	-	-	V	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =30V, $V_{GS}$ =0V	-	-	1	μA	
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±20V, $V_{DS}$ =0V	-	-	±100	nA	
On Characteristics (Note 3)	····		•	•			



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Parameter	Symbol	Condition	Min	Тур	Max	Unit
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250µA	1.0	1.6	2.5	V
Drain-Source On-State Resistance	D	V <sub>GS</sub> =10V, I <sub>D</sub> =13A	-	9.5	12	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =13A	-	15	20	mΩ
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =5V,I <sub>D</sub> =13A	26	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>		-	1066	-	PF
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =15V,V <sub>GS</sub> =0V, F=1.0MHz	-	160	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>		-	137	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	5	-	nS
Turn-on Rise Time	tr	$V_{DD}$ =15V, R <sub>L</sub> =1.2 $\Omega$	-	12	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_{G}$ =3 $\Omega$	-	19	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	6	-	nS
Total Gate Charge	Qg		-	24	-	nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = 15V, I_D = 13A,$	-	3.5	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	6	-	nC
Drain-Source Diode Characteristics						•
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =13A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	13	A
Reverse Recovery Time	t <sub>rr</sub>	T <sub>J</sub> = 25°C, I <sub>F</sub> =13A	-	29	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs <sup>(Note3)</sup>	-	50	-	nC
Forward Turn-On Time	t <sub>on</sub>	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

### Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

**2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.

**3.** Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.

4. Guaranteed by design, not subject to production

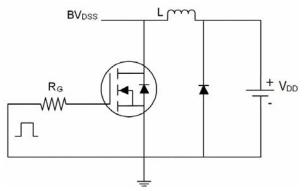
5. EAS condition:Tj=25  $^\circ \!\! C$  ,V\_DD=15V,V\_G=10V,L=0.5mH,Rg=25\Omega

6. The spike duty cycle 5% max, limited by junction temperature T\_J(MAX)=125  $^\circ\,$  C

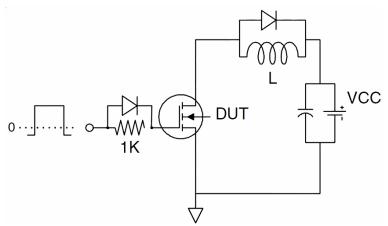


# **Test circuit**

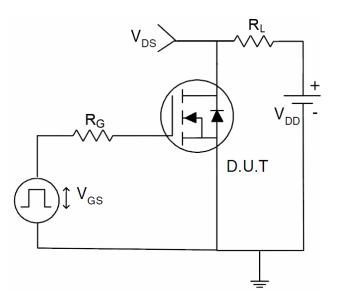
1)  $E_{AS}$  test Circuits



2) Gate charge test Circuit:

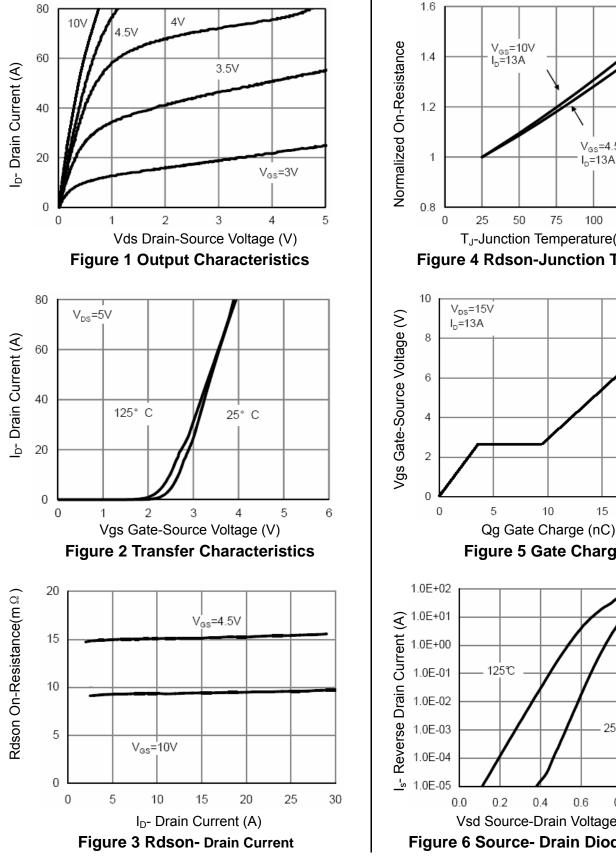


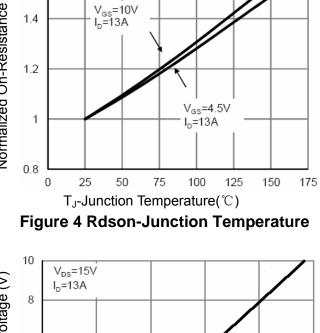
3) Switch Time Test Circuit:

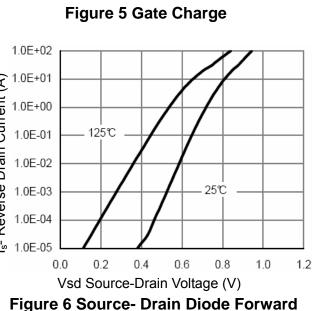












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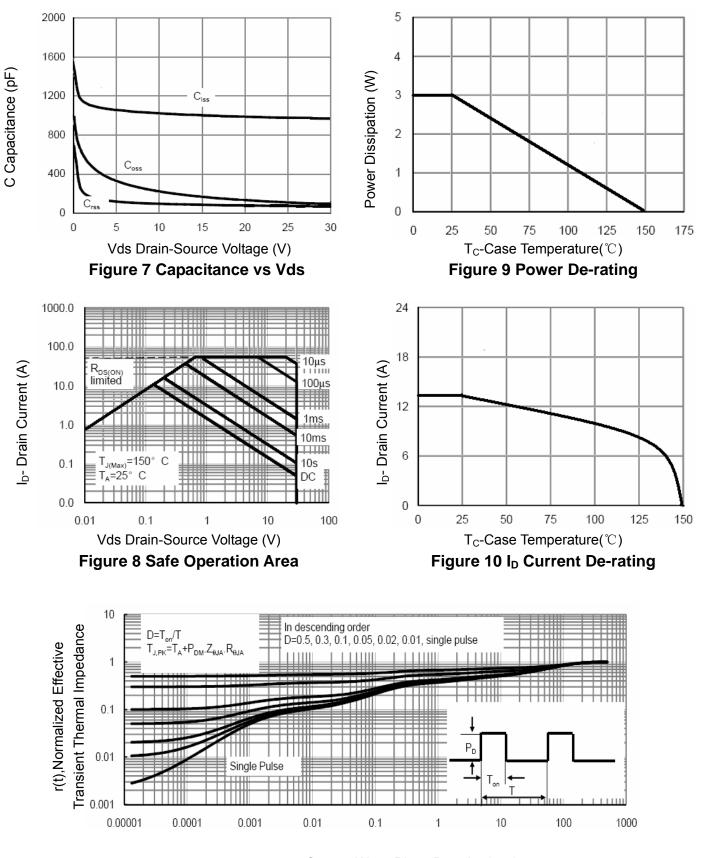
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20

25



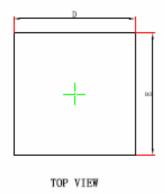
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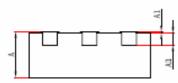


Square Wave Pluse Duration(sec) Figure 11 Normalized Maximum Transient Thermal Impedance

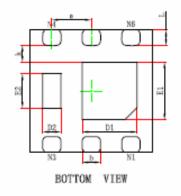


## DFN2X2-6L Package Information



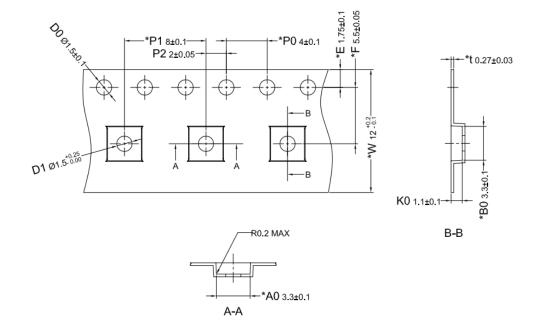


SIDE VIEW



Symbol	Dimensions Ir	n Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
A	0.700	0.800	0.028	0.031	
A1	0.000	0.050	0.000	0.002	
A3	0.203	REF.	0.008	REF.	
D	1.924	2.076	0.076	0.082	
E	1.924	2.076	0.076	0.082	
D1	0.800	1.000	0.031	0.039	
E1	0.850	1.050	0.033	0.041	
D2	0.200	0.400	0.008	0.016	
E2	0.460	0.660	0.018	0.026	
k	0.200MIN.		0.008MIN.		
b	0.250	0.350	0.010	0.014	
е	0.650TYP.		0.026TYP.		
L	0.174	0.326	0.007	0.013	







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